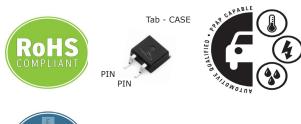


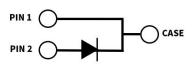
E-Series Automotive 650 V, 20 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher efficiency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.







Part Number	Package	Marking
E6D20065G	TO-263-2	E6D20065G

Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Automotive Qualified (AEC Q101) and PPAP Capable

Typical Applications

- Interleaved or Bridgless PFC
- DC/DC On Board Battery Chargers
- Boost for PFC & DC-DC Stages
- AC/DC On Board Chargers
- PFC Output Rectification

Maximum Ratings (T_c = 25°C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes	
Repetitive Peak Reverse Voltage	V _{RRM}	650				
Surge Peak Reverse Voltage	V _{RSM}	650	V			
DC Blocking Voltage	V _{DC}	650				
		68		T _c = 25 °C		
Continuous Forward Current	I _F	34		T _c = 125 °C	Fig. 3	
		21	Α	T _c = 150 °C		
Repetitive Peak Forward Surge		78		T _c = 25 °C, t _p = 10 ms, Half Sine Wave		
Current	FRM	45		T _c = 110 °C, t _p = 10 ms, Half Sine Wave		
Non-Repetitive Forward Surge		149		$T_c = 25 ^{\circ}\text{C}$, $t_p = 10 \text{ms}$, Half Sine Wave		
Current	FSM	131	Α	$T_c = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}, \text{Half Sine Wave}$		
		183		T _c = 25 °C		
Power Dissipation	P _{tot}	79	W	T _c = 110 °C	Fig. 4	
*21	63.11	111	A 2	$T_c = 25 {}^{\circ}\text{C}, t_p = 10 \text{ms}$		
i²t value	∫i²dt	86	A ² s	$T_{c} = 110 {}^{\circ}\text{C}, t_{p} = 10 \text{ms}$		

Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
Forward Voltage		1.3	1.5	V	I _F = 20 A, T _j = 25 °C	Fig. 1
	V _F	1.4	1.6		I _F = 20 A, T _j = 175 °C	
Reverse Current		10	75		$V_R = 650 \text{ V}, T_j = 25 \text{ °C}$	F. 0
	I _R	40	300	μΑ	$V_R = 650 \text{ V}, T_j = 175 \text{ °C}$	Fig. 2
Total Capacitive Charge	Q _c	70		nC	$V_R = 400 \text{ V}, T_j = 25 \text{ °C}$	Fig. 5
		1277			$V_R = 0 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
Total Capacitance	c	137		pF	$V_R = 200 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	Fig. 6
		107			$V_R = 400 \text{ V}, T_j = 25 \text{ °C}, f = 1 \text{ MHz}$	
Capacitance Stored Energy	E _c	10.7		μJ	V _R = 400 V	Fig. 7

Notes:

SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Unit	Notes
Thermal Resistance, Junction to Case (Typical)	R _{θ, JC (TYP)}	0.63	°C/W	
Thermal Resistance, Junction to Case (Max)	R _{0, JC (MAX)}	0.82	°C/W	
Junction Temperature	T _j	-55 to +175	0.6	
Case & Storage Temperature	T _c	-55 to +175	°C	

Typical Performance

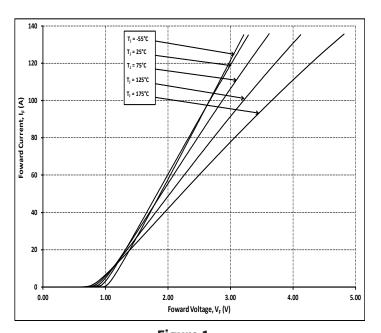
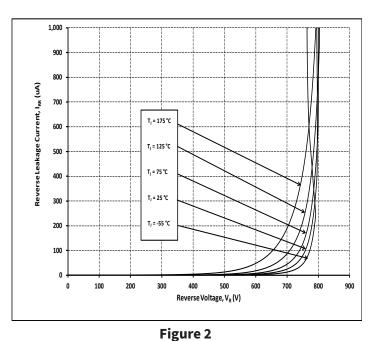


Figure 1Forward Characteristics



Reverse Characteristics

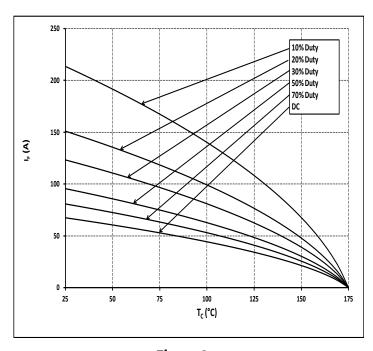


Figure 3Current Derating

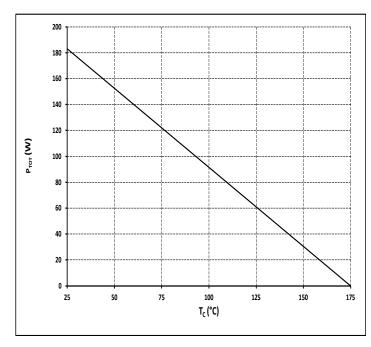


Figure 4Power Derating

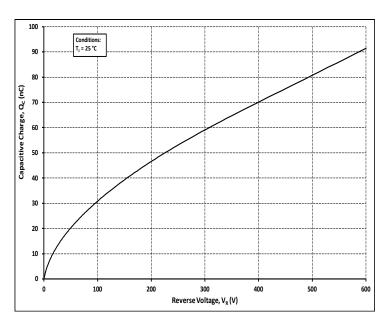


Figure 5Total Capacitance vs. Reverse Voltage

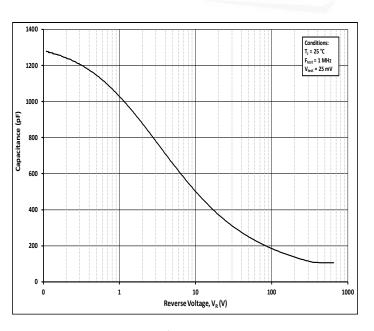


Figure 6Capacitace vs. Reverse Voltage

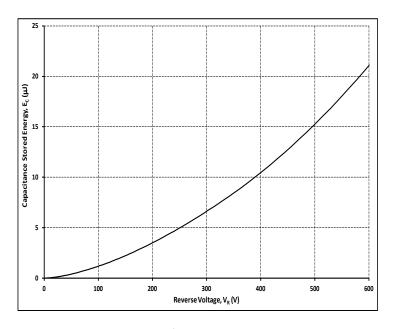


Figure 7Capacitance Stored Energy

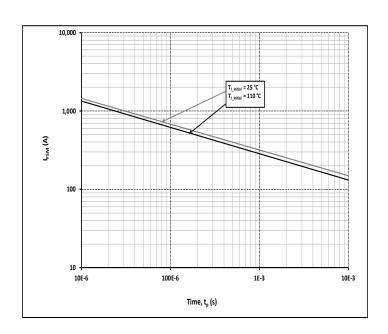


Figure 8Non Repetitive Peak Forward Surge Current versus Pulse Duration (sinsusoidal waveform)

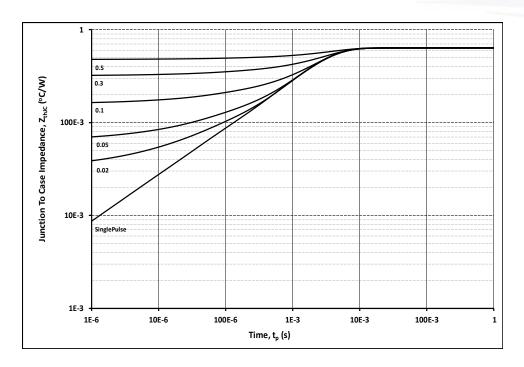
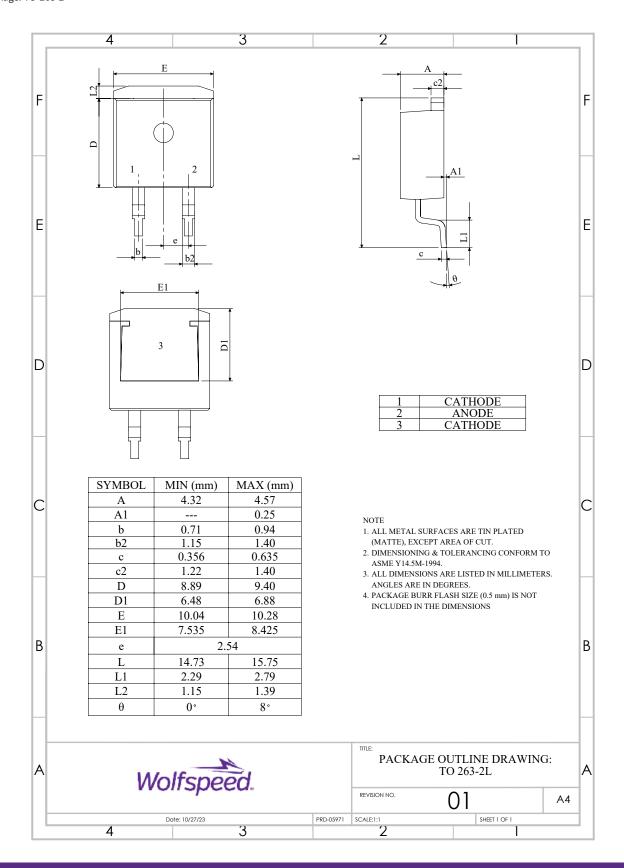


Figure 9Transient Thermal Impedance

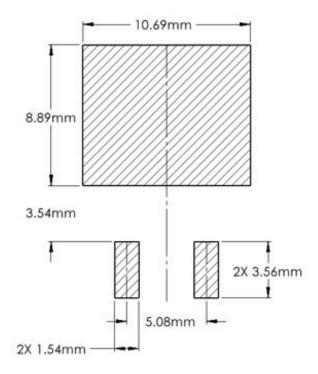
Package Dimensions & Pin-Out

Package: TO-263-2



Recommended Solder Pad Layout

Primary dimensions shown in mm.



Product Ordering Information

Order Number	Packing Type
E6D20065G-TR	Tape & Reel
E6D20065G	Tube

Revision History

Document Version	Date of Release	Description of Changes
1	February 2024	Initial Release
2	February - 2025	Legal Disclaimer Updated

Notes & Disclaimer

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